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## Semiconductor Optical Amplifier Device (Switch-type)

IPSAD1302/ IPSAD1502 (1310nm/1550nm)

## Features

- Wide Optical Bandwidth
- Fast Switching Speed
- High Extinction Ratio
- Low Polarization Sensitivity
- MQW or Bulk Structure



## Applications

- Optical Gate Switching with Loss Compensation
- Wavelength Routing
- Matrix Switch


## IPSAD1302 Switch-type SOA Device Specifications

| Parameter | Symbol | Specifications |  |  | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. |  |
| Drive Current | $\mathrm{I}_{\mathrm{F}}$ |  | 100 | 150 | mA |
| Operating Peak Wavelength | $\lambda_{\mathrm{p}}$ | 1280 |  | 1340 | nm |
| 3 dB Optical Bandwidth | $\Delta \lambda_{3 \mathrm{~dB}}$ | 50 |  |  | nm |
| Small Signal Gain at $\lambda_{\mathrm{p}} @-25 \mathrm{dBm}$ <br> Signal | $\mathrm{G}_{\mathrm{max}}$ |  | 10 |  | dB |
| Gain Ripple with Respect to $\lambda$ |  |  |  |  |  |
| Saturation Output Power | $\Delta \mathrm{G}$ |  | 0.2 | 0.5 | dB |
| Noise Figure | $\mathrm{P}_{\mathrm{sat}}$ | 4 |  |  | dBm |
| Polarization Dependent Gain | NF |  | 8 |  | dB |
| Extinction Ratio | PDG |  | 0.2 | 0.5 | dB |
| Switching Properties | Rise Time | ER | 40 |  |  |

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## IPSAD1502 Switch-type SOA Device Specifications

| Parameter | Symbol | Specifications |  |  | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
|  |  | Typ. | Max. |  |  |
| Drive Current | $\mathrm{I}_{\mathrm{F}}$ |  | 120 | 180 | mA |
| Operating Peak Wavelength | $\lambda_{\mathrm{p}}$ | 1510 |  | 1570 | nm |
| 3 dB Optical Bandwidth | $\Delta \lambda_{3 \mathrm{~dB}}$ | 50 |  |  | nm |
| Small Signal Gain at $\lambda_{\mathrm{p}} @ \operatorname{dBm}$ <br> Signal | $\mathrm{G}_{\max }$ |  | 10 |  | dB |
| Gain Ripple with Respect to $\lambda$ |  |  |  |  |  |
| Saturation Output Power | $\Delta \mathrm{G}$ |  | 0.2 | 0.5 | dB |
| Noise Figure | $\mathrm{P}_{\mathrm{sat}}$ | 3 |  |  | dBm |
| Polarization Dependent Gain | NF |  | 10 |  | dB |
| Extinction Ratio | PDG |  | 0.2 | 0.5 | dB |
| Switching Properties | Rise Time | ER | 40 |  |  |

## Absolute Maximum Ratings

| Parameter | Min. | Max. | Unit |
| :--- | :---: | :---: | :---: |
| Operating Temperature | -20 | 70 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |
| SOA Forward Current |  | 300 | mA |
| SOA Reverse Voltage |  | 2.5 | V |
| TEC Drive Current |  | 1.5 | A |
| TEC Drive Voltage | 3.6 | V |  |
| Thermistor Resistance | $10 \mathrm{k} \Omega @, 25^{\circ} \mathrm{C}$ |  |  |
| SOA Chip Temperature Setting | $25^{\circ} \mathrm{C}$ |  |  |
| Fiber Type | SMF |  |  |
| Fiber Jacket | 14 -pin Butterfly |  |  |
| Package |  |  |  |

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## Package Dimensions



## Pin Definition

| Pin | 14-pin Butterfly |
| :---: | :---: |
| 1 | TEC $(+)$ |
| 2 | NC |
| 3 | Thermistor |
| 4 | Thermistor |
| 5 | NC |
| 6 | NC |
| 7 | NC |
| 8 | NC |
| 9 | NC |
| 10 | SOA $(+)$ |
| 11 | SOA(-) |
| 12 | NC |
| 13 | Case |
| 14 | TEC(-) |

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## Part Numbering Structure



Example: IPSAD1302-110: 1310 nm Switch-type SOA in 14-pin Butterfly Package with $900 \mu \mathrm{~m}$ SM Fiber with no Connectors.

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